### Vishay High Power Products

# HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 16 A



- Ultrafast recovery
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- Specified at operating conditions
- Designed and qualified for industrial level

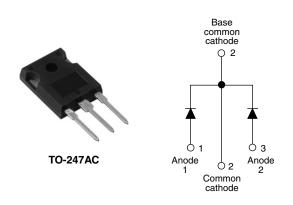
#### BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

#### DESCRIPTION

HFA32PA120C is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 16 A per leg continuous current, the HFA32PA120C is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>BBM</sub>) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA32PA120C is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V <sub>R</sub>		1200	V		
Maximum continuous forward current per leg	IF	T <sub>C</sub> = 100 °C	16			
per device			32	А		
Single pulse forward current	I <sub>FSM</sub>		190	А		
Maximum repetitive forward current	I <sub>FRM</sub>		64			
Maximum power discipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	151	С°С		
Maximum power dissipation		T <sub>C</sub> = 100 °C	60	1		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	W		



SHA

PRODUCT SUMMARY					
V <sub>R</sub> per leg	1200 V				
V <sub>F</sub> at 16 A at 25 °C	3.0 V				
I <sub>F(AV)</sub>	2 x 16 A				
t <sub>rr</sub> (typical) per leg	5.8 A				
T <sub>J</sub> (maximum)	150 °C				
Q <sub>rr</sub> (typical) per leg	260 nC				
I <sub>RRM</sub> (typical) per leg	5.8 A				

# HFA32PA120C



# Vishay High Power Products

### HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 16 A

<b>ELECTRICAL SPECIFICATIONS PER LEG</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		1200	-	-	
Maximum forward voltage V <sub>f</sub>	V <sub>FM</sub>	I <sub>F</sub> = 16 A	See fig. 1	-	2.5	3.0	V
		I <sub>F</sub> = 32 A		-	3.2	3.93	
		I <sub>F</sub> = 16 A, T <sub>J</sub> = 125 °C		-	2.3	2.7	
Maximum reverse			Coofig 0	-	0.75	20	
leakage current	I <sub>RM</sub>	$T_J = 125 \ ^{\circ}C, V_R = 0.8 \ x \ V_R$ rated	See fig. 2	-	375	2000	μΑ
Junction capacitance	CT	V <sub>R</sub> = 200 V	See fig. 3	-	27	40	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8.0 -		nH			

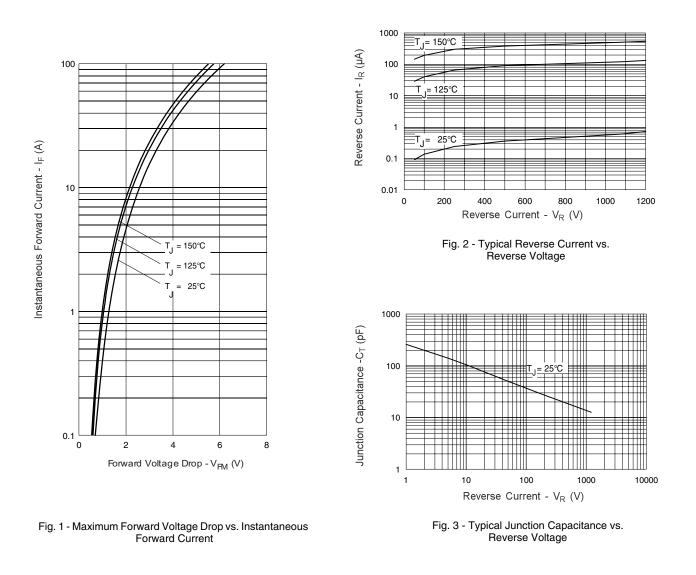
<b>DYNAMIC RECOVERY CHARACTERISTICS PER LEG</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time See fig. 5, 10	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	30	-	
	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 16 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	90	135	ns
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	164	245	
Peak recovery current See fig. 6	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	5.8	10	A nC A/μs
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	8.3	15	
Reverse recovery charge See fig. 7	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	260	675	
	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	680	1838	
Peak rate of fall of recovery current during t <sub>b</sub> See fig. 8	dI <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	120	-	
	dl <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	76	-	

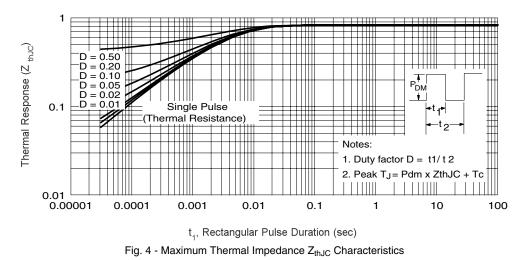
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.83	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount -		-	80	K/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.50	-	
Weight			-	2.0	-	g
weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC (JEDEC)	HFA32PA120C		•	



### HEXFRED<sup>®</sup> Vis Ultrafast Soft Recovery Diode, 2 x 16 A

Vishay High Power Products





# HFA32PA120C

## Vishay High Power Products

HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 16 A

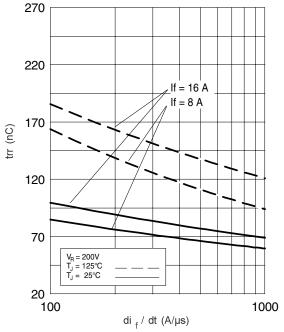


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt (Per Leg)

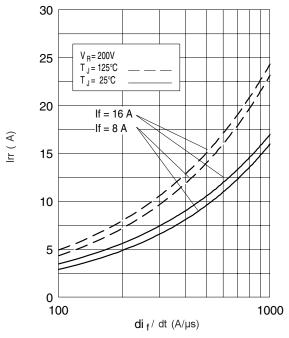
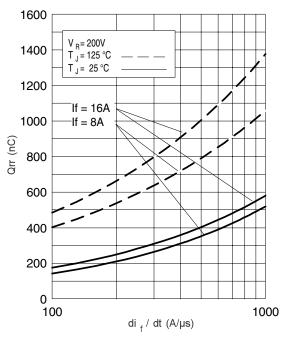
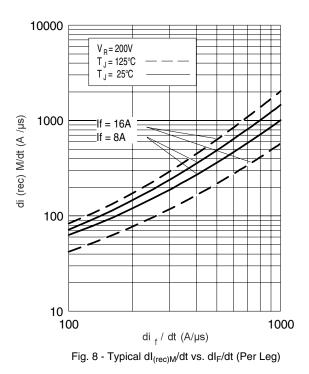


Fig. 6 - Typical Recovery Current vs.  $dI_F/dt$  (Per Leg)



VISHAY

Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$  (Per Leg)





HEXFRED<sup>®</sup> Vishay High Power Products Ultrafast Soft Recovery Diode, 2 x 16 A

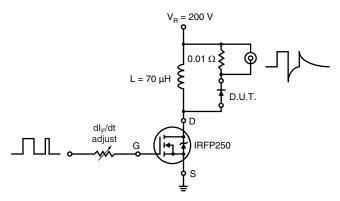


Fig. 9 - Reverse Recovery Parameter Test Circuit

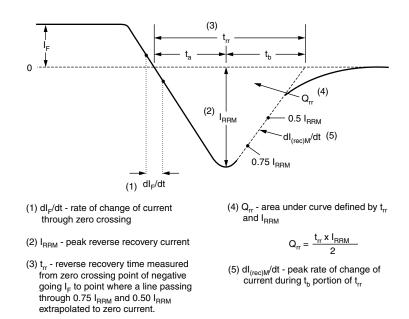


Fig. 10 - Reverse Recovery Waveform and Definitions

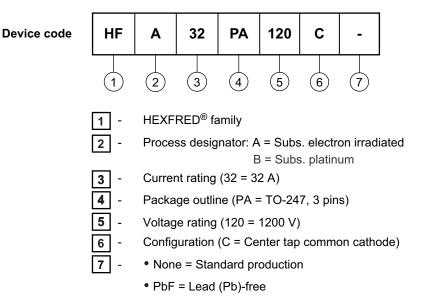
## HFA32PA120C



Vishay High Power Products

HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 16 A

#### ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95223				
Part marking information	http://www.vishay.com/doc?95226			



Vishay

# Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.